



# ADVANCED ELECTRONICS LABORATORIES

CENTRE FOR ADVANCED ELECTRONICS &  
PHOTOVOLTAIC ENGINEERING (CAEPE)



## 4<sup>th</sup> WORKSHOP ON CHIP PROCESS DESIGN & ANALYTICAL TESTING

In continuation to the previous workshops in last three years, Advanced Electronics Laboratories offer a 6-days workshop on **CHIP PROCESS DESIGN AND ANALYTICAL TESTING** for all of its graduate students who have entered into research phase from SUMMERS 2017. The lab engineers and faculty members from Faculty of Engineering & Technology, Faculty of Basic and Applied Sciences and Iqra College are also encouraged to attend the workshop to gain the knowledge of technological processes of IC design as well as post-process reliability, efficiency and failure analysis of circuits, devices and nano-systems. The training will be conducted on internationally licensed softwares and R&D grade sophisticated machines in the laboratories.

### Day 1 & Day 2:

Introduction to State of the art  
Licenced tools

- Why Device Design is phenomenally important?
- CMOS Scaling & Efficiency, IC Fab specific design and processes
- Road to technology files, ATHENA, ATLAS, BLAZE, LUMINOUS, ORGAN

### Day 3 & Day 4:

Advanced Electrical/Electro-  
Optical Characterizations

- Nano chip reliability grade Hall Effect Chip level Characterization
- Multi-head Probe station assembled with variety of different device/circuit level techniques
- Introduction to van der paw, Hall and Clover leaf paterrens for Hall Analysis
- Effect of Magnitization, Electric Field, Transient of bais sweeps, Resistivity/Conductivity Scans, Charge Carrier Cocentrations, Eлектon/Hole Mobilities for Chip level assesment
- Practical hands on Open Circuit Voltage (Voc) and Short Circuit Current (Isc) for PV devices
- Effect of Current Voltage (I-V) and Capcitanace Voltage (C-V) profiling for research prospects
- Introduction to very sophisticated characterization techniques; Charge Deep Level Transient Spectroscopy (Q-DLTS) and Photo stimulated Internal Field Transient Spectroscopy
- Issues in device reliability

### Day 5:

Optical Assessment & Rapid  
Thermal Processing

- Optical profilometry and scanning of optical parameters like refractive index, dielectrics, extinction coefficients, critical thickness at subnano scales
- Optical Characterization of Si based Quadrant photo detector (basic overview) and spectroscopic ellipsometry
- Hands on with multiple devices and samples, working out the electro-optics
- Experimentation on Rapid thermal annealing machine, Technique of RT-CVD, RTO and RTP, ITRS specific Thermal budget

### Day 6:

Back End Processes

- Device's Metalization, Cleaning, Etching, Spin Coating, Baking.
- Wet chemistry, contact development, Physical Layer Depostion, packaging etc.

### AELP HIGHLIGHTS

- State of the art Device Design and Process Characterization Facilities under one roof
- Over 100 running scientific projects besides over 400 of Quality Assurance runs
- Problems converging on the forefronts of Micro & Nano Electronics, Photonics & Optoelectronics, Photovoltaic Energy Engineering and Sensing & Detection
- 34% of the total running projects are from outside the IIUI including other universities, industry and national scientific organizations

**Days: 10<sup>th</sup> to 15<sup>th</sup> July, 2017**

**Time: 10:00 AM – 4:00 PM**

**Venue:**

**Advanced Electronics Laboratories, Ibn-Khaldun  
Block, IIUI**

**For Confirmation and Queries**

**Contact: Engr. Shoaib Alam**

**Phone # 051-9019927; 03015785837**

**Email: aelp@iiu.edu.pk**

**INTERNATIONAL ISLAMIC UNIVERSITY - ISLAMABAD**

Ibn Khaldun Block, Sector H-10, Islamabad - Pakistan Ph: +92-51-9019453, Fax: +92-51-9258019  
[www.iiu.edu.pk/aelp](http://www.iiu.edu.pk/aelp)